Product data sheet

1. General description

Power Schottky diode in TO252 (DPAK) surface-mountable plastic package.





2. Features and benefits

- High junction temperature up to 175°C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit					
Absolute	Absolute maximum rating											
V_{RRM}	repetitive peak reverse voltage			150			V					
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 152$ °C; Fig. 1; Fig. 2; Fig. 3		20			Α					
Symbol	Parameter	Conditions	Notes	Min Typ Max			Unit					
Static ch	Static characteristics											
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u>		-	0.87	0.98	V					
I _R	reverse current	V _R = 150 V; T _j = 25 °C		- 0.04 5		5	μA					

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode		K A
2	K	cathode		K —— A 001aaa020
3	А	anode		
mb	К	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WN3S20150DT	TO252	WN3S20150DTJ	Reel	2500	TO252d	07-Sep-2022

7. Marking

Table 4. Marking codes

Type number	Marking codes
WN3S20150DT	WN3S20 150DT

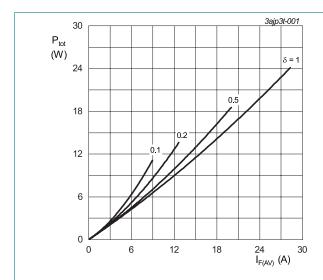
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

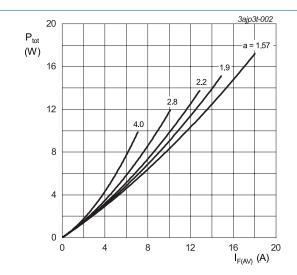
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			150	V
V_{RWM}	crest working reverse voltage			150	V
V_R	reverse voltage	DC		150	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 152 °C; Fig. 1; Fig. 2; Fig. 3		20	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		256	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		281.6	Α
T _{stg}	storage temperature			-40 to 175	°C
T _j	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.671 \text{ V; } R_s = 0.0064 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}$ / $I_{F(AV)}$ V_o = 0.671 V; R_s = 0.0064 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

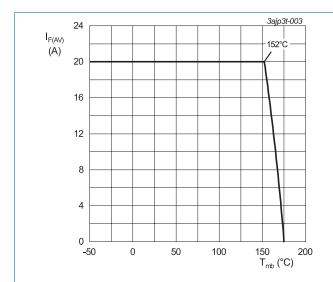


Fig. 3. Average forward current as a function of mounting base temperature; maximum values

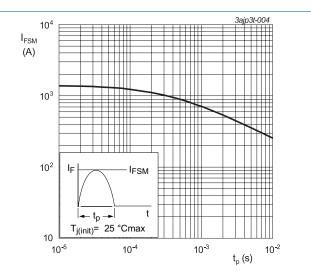


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	1.23	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	50	-	K/W

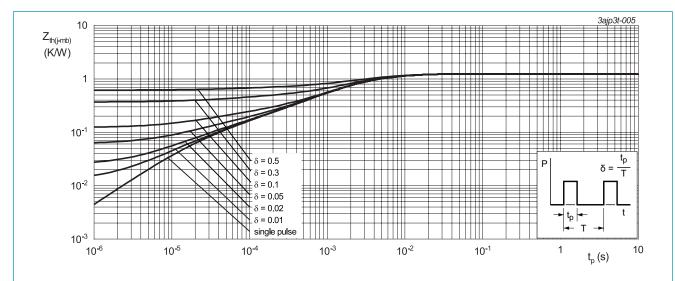
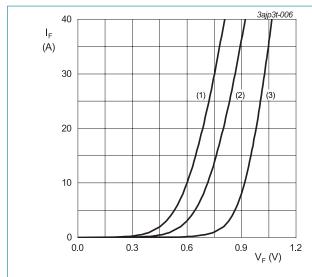


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static characteristics								
V_{F}	forward voltage $I_F = 20 \text{ A}; T_j = 25 \text{ °C}; Fig. 6$			-	0.87	0.98	V	
		I _F = 20 A; T _j = 125 °C; <u>Fig. 6</u>		-	0.75	-	V	
I _R	reverse current	V _R = 150 V; T _j = 25 °C; <u>Fig. 7</u> ; <u>Fig. 8</u>		-	0.04	5	μΑ	
		V _R = 150 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u>		-	0.2	-	mA	

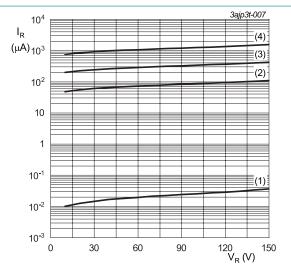


 $V_0 = 0.671 \text{ V}; R_s = 0.0064 \Omega$

(1) $T_j = 175$ °C; typical values (2) $T_j = 175$ °C; maximum values

(3) $T_i = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

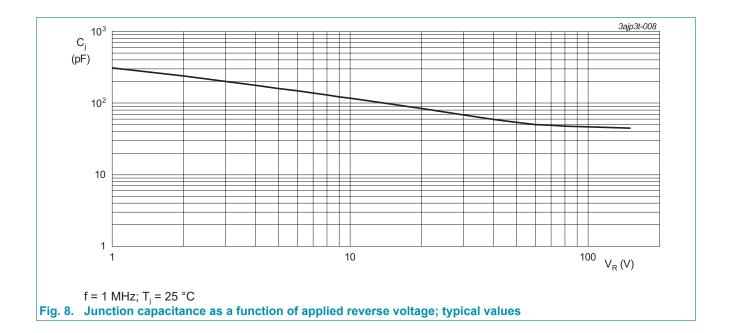


(1) T_i = 25 °C; typical values

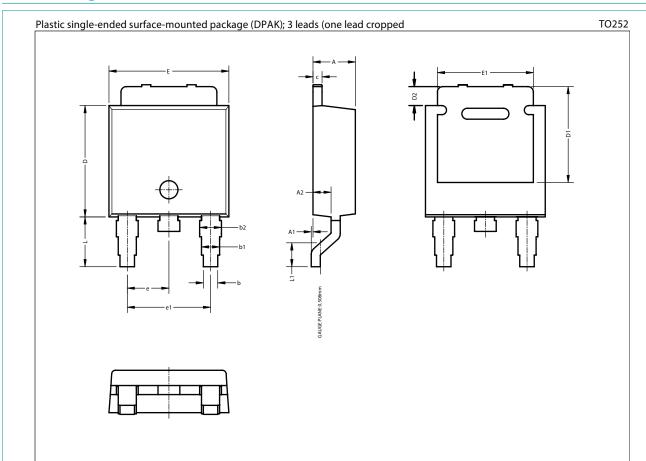
(2) $T_j = 125$ °C; typical values (3) $T_j = 150$ °C; typical values

(4) T_i = 175 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; typical values



11. Package outline



Note:

1. All dimensions do not include mold flash & gate remain and metal protrusion.

	Unit	Α	A1	A2	b	b1	b2	С	D	D1	D2	E	E1	е	e1	L	L1
	min mm nom	2.16	0.00	0.90	0.70	0.86	1.06	0.46	5.97	5.05	0.98	6.45	5.20	2.30	4.60	2.60	1.25
Ĺ		2.41	0.10	1.10	0.90	1.11	1.32	0.58	6.22	5.35	1.18	6.75				2.90	1.65

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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